

BU807

BU807 Information



Part Number	BU807	
Manufacturer	STMicroelectronics	
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single	
Description	TRANS NPN DARL 150V 8A TO-220	
Package	TO-220-3	
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com	



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For Reference Only

Certified Quality

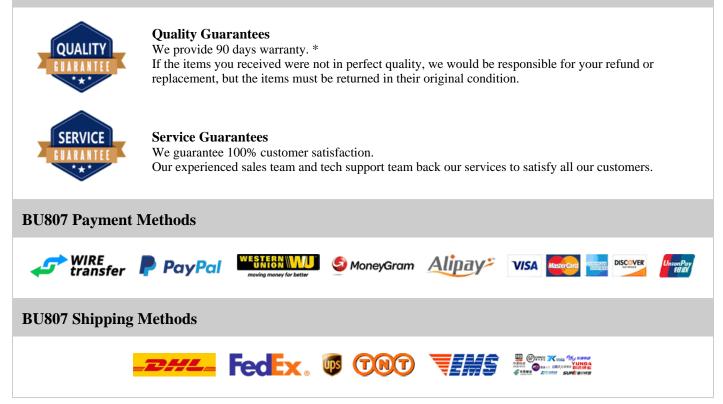
Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



BU807 Specifications

Manufacturer Part NumberBU807ManufacturerSTMicroelectronicsCategoryDiscrete Semiconductor ProductsTransistors - Bipolar (BJT) - SinglePackageTo-220-3Series-Transistor TypeNPN - DarlingtonCurrent - Collector (Ic) (Max)8AVoltage - Collector Emitter Breakdown (Max)150VVce Saturation (Max) @ Ib, Ic1.5V @ 50mA, 5ACurrent - Collector Cutoff (Max)00µADC Current Gain (hFE) (Min) @ Ic, Vce-Power - Max60WFrequency - Transition-Operating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTo-220-3Supplier Device PackageTo-220AB		
CategoryDiscrete Semiconductor ProductsTransistors - Bipolar (BJT) - SinglePackageTO-220-3Series-Transistor TypeNPN - DarlingtonCurrent - Collector (Lc) (Max)8AVoltage - Collector Emitter Breakdown (Max)150VVce Saturation (Max) @ Ib, Ic1.5V @ 50mA, 5ACurrent - Collector Cutoff (Max)0µADC Current Gain (hFE) (Min) @ Ic, Vce-Power - Max60WFrequency - Transition-Operating Temperature150° (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220-8	Manufacturer Part Number	BU807
Transistor - Bipolar (BJT) - SinglePackageTO-220-3Series-Transistor TypeNPN - DarlingtonCurrent - Collector (Ic) (Max)8AVoltage - Collector Emitter Breakdown (Max)150VVce Saturation (Max) @ Ib, Ic1.5V @ 50mA, 5ACurrent - Collector Cutoff (Max)00µADC Current Gain (hFE) (Min) @ Ic, Vce-Power - Max60WFrequency - Transition-Operating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220AB	Manufacturer	STMicroelectronics
PackageTO-220-3Series-Transistor TypeNPN - DarlingtonCurrent - Collector (Lc) (Max)8AVoltage - Collector Emitter Breakdown (Max)150VVce Saturation (Max) @ Ib, Ic1.5V @ 50mA, 5ACurrent - Collector Cutoff (Max)100µADC Current Gain (hFE) (Min) @ Ic, Vce-Power - Max60WFrequency - Transition-Operating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220AB	Category	Discrete Semiconductor Products
Series-Stries-Transistor TypeNPN - DarlingtonCurrent - Collector (Indx)8AVoltage - Collector Emitter Breakdown (Max)150VVce Saturation (Max) @ Ib, Ic1.5V @ 50mA, 5ACurrent - Collector Cutoff (Max)10µADC Current Gain (hFE) (Min) @ Ic, Vce-Power - Max60WFrequency - Transition-Operating Temperature150°C (TJ)Mounting TypeThough HolePackage / CaseTO-220-3BSupplier Device PackageTO-220AB		Transistors - Bipolar (BJT) - Single
Transistor TypeNPN - DarlingtonTransistor TypeNPN - DarlingtonCurrent - Collector (L) (Max)8AVoltage - Collector Emitter Breakdown (Max)150VVce Saturation (Max) @ Ib, Ic1.5V @ 50mA, 5ACurrent - Collector Cutoff (Max)100µADC Current Gain (hFE) (Min @ Ic, Vce-Power - Max60WFrequency - Transition-Operating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220AB	Package	TO-220-3
Current - Collector (Ic) (Max)8AVoltage - Collector Emitter Breakdown (Max)150VVce Saturation (Max) @ Ib, Ic1.5V @ 50mA, 5ACurrent - Collector Cutoff (Max)100µADC Current Gain (hFE) (Min) @ Ic, Vce-Power - Max60WFrequency - Transition-Operating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220AB	Series	-
Voltage - Collector Emitter Breakdown (Max)150VVce Saturation (Max) @ Ib, Ic1.5V @ 50mA, 5ACurrent - Collector Cutoff (Max)100µADC Current Gain (hFE) (Min) @ Ic, Vce-Power - Max60WFrequency - Transition-Operating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220AB	Transistor Type	NPN - Darlington
Yce Saturation (Max) @ Ib, Ic1.5V @ 50mA, 5ACurrent - Collector Cutoff (Max)100μADC Current Gain (hFE) (Min) @ Ic, Vce-Power - Max60WFrequency - Transition60WOperating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220AB	Current - Collector (Ic) (Max)	8A
Current - Collector Cutoff (Max)100μADC Current Gain (hFE) (Min) @ Ic, Vce-Power - Max60WFrequency - Transition-Operating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220AB	Voltage - Collector Emitter Breakdown (Max)	150V
DC Current Gain (hFE) (Min) @ Ic, Vce-Power - Max60WFrequency - Transition-Operating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220AB	Vce Saturation (Max) @ Ib, Ic	1.5V @ 50mA, 5A
Power - Max60WFrequency - Transition-Operating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220AB	Current - Collector Cutoff (Max)	100μΑ
Frequency - Transition-Operating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220AB	DC Current Gain (hFE) (Min) @ Ic, Vce	-
Operating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220AB	Power - Max	60W
Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220AB	Frequency - Transition	-
Package / CaseTO-220-3Supplier Device PackageTO-220AB	Operating Temperature	150°C (TJ)
Supplier Device Package TO-220AB	Mounting Type	Through Hole
	Package / Case	TO-220-3
Report errors?	Supplier Device Package	TO-220AB
		Report errors?

BU807 Guarantees



If you have any question about BU807, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com